

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

U.S. Patent Application of)
a et al.)) Art Unit 1792
cation Number: 10/549,683)
September 19, 2005)) Examiner) Song, Matthew J.
METHOD OF GROWING)
SEMICONDUCTOR CRYSTAL)
)
ney Docket No. HIRA.0204)
	cation Number: 10/549,683 September 19, 2005 METHOD OF GROWING SEMICONDUCTOR CRYSTAL

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §§ 1.56 and 1.97, this Information Disclosure Statement is submitted in the above-identified patent application. A listing of documents to be published on the face of any patent granted from this application is submitted herewith on Form PTO-1449. Any other documents or information submitted for consideration by the Examiner are listed in this paper. A copy of each foreign patent, or each publication or portion thereof listed or herein identified, submitted herewith.

This Information Disclosure Statement is submitted with the initial filing of the RCE. Accordingly, no fee is due or payable at this time.

The Examiner is requested to acknowledge consideration of the information provided in this paper in accordance with prescribed procedures.

Please charge any additional fees or credit any overpayments in connection with this paper to Deposit Account No. 08-1480.

Respectfully submitted,

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REED SMITH LLP

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